

Supplemental Materials

Towards accurate orbital-free simulations: a generalized gradient approximation for the noninteracting free energy density functional

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I. NUMBER OF BANDS IN THE SIMULATIONS

In the static lattice calculations, the number of bands used for *fcc* Al and *cd* Si at each temperature is shown in Table I. Table II shows the corresponding values used in the deuterium (D) AIMD simulations at two densities. The result is that the smallest occupation number used always was less than 10^{-6} .

TABLE I. The number of bands used for *fcc* Al at $\rho = 2.3 \text{ g/cm}^3$ and *cd* Si at $\rho = 2.0 \text{ g/cm}^3$. For higher densities, the same were used.

T (eV)	<i>fcc</i> Al	<i>cd</i> Si
01	20	60
02	50	120
03	90	160
04	100	240
05	150	320
06	180	400
07	200	440
08	220	500
09	240	540
10	260	650

TABLE II. The number of bands used for deuterium (D) at various conditions. The simulation cell contains 128 D atoms.

T (kK)	$r_s = 1.1 \text{ bohr}$	$r_s = 1.4 \text{ bohr}$
5	90	110
10	90	110
15.625	100	130
31.25	160	210
62.5	200	480
95.25	340	600
125	470	

II. VIOLATIONS OF THERMODYNAMIC RELATIONS

Because the construction of the non-interacting free energy starts with the ground-state non-interacting kinetic energy (KE) functional, once the kinetic free energy generalization is done, there is a route to the non-interacting entropic

contribution. It starts with enforcement of the Maxwell relation

$$S_s^{\text{GGA}} = - \left. \frac{\partial \mathcal{F}_s^{\text{GGA}}}{\partial T} \right|_V = - \left. \frac{\partial \mathcal{T}_s^{\text{GGA}}}{\partial T} \right|_V + \left. \frac{\partial (T S_s^{\text{GGA}})}{\partial T} \right|_V. \quad (1)$$

That gives

$$\left. \frac{\partial \mathcal{T}_s^{\text{GGA}}}{\partial T} \right|_V = T \left. \frac{\partial S_s^{\text{GGA}}}{\partial T} \right|_V. \quad (2)$$

and thus to a required relationship between the enhancement factors F_τ and F_σ such that the two are proper kinetic and entropic contributions respectively, namely

$$\begin{aligned} \xi'(t) F_\tau(s_\tau) + \xi(t) F'_\tau(s_\tau) \frac{\partial s_\tau}{\partial t} \\ = -\frac{1}{t} \zeta(t) F_\sigma(s_\sigma) + \zeta'(t) F_\sigma(s_\sigma) + \zeta(t) F'_\sigma(s_\sigma) \frac{\partial s_\sigma}{\partial t}, \end{aligned} \quad (3)$$

This last relationship is Eq. (35) of Ref. [1]. Even if satisfied by a particular approximation, that clarity of identification does not provide any guarantee on the accuracy or inaccuracy of the non-interacting free energy provided by the two approximations combined.

The LKTF functional developed in this work does not satisfy Eq. (3) exactly. The same is true with the earlier VT84F² and KST2¹ functionals. All three used the approximation

$$F_\sigma(s_\sigma) = 2 - F_\tau(s_\sigma) \quad (4)$$

Two questions then arise. To what extent does use of this approximation result in loss of identification of the F_τ and F_σ terms as kinetic and entropic and does such loss matter for the overall accuracy of the approximation?

For insight at least as to the first question, we compare the left- and right-hand sides of Eq. (3) to see the difference. Fig. 1 shows the results for KST2. This is a reproduction and extension of Fig. 3 in Ref.[1]. (We note that the analytical representations of the functions $\xi(t)$ and $\zeta(t)$ used here are from Ref. [3], not the older fits given by Perrot and Dharma-wardana⁴ and extended.) For small s (weak spatial density variation) and low t , Eq. (3) is violated only mildly. As s increases, the largest deviation happens around $t = 0.4$ for $s = 1.0$. Similarly, Fig. 2 shows that LKTF exhibits vanishing left-hand versus right-hand side differences, for $s = 0.5$. For $s = 2.0$, the difference reaches its maximum magnitude around $t = 0.4$.

Though this clearly indicates a failure of the Eq. (4) approximation to be a solution of Eq. (3) when used to construct

LKTF from ground-state LKT, how to interpret that failure is not entirely clear. What the non-zero difference, LHS - RHS of Eq. (3), shows is only that the combination of a given pair F_τ, F_σ with the “2 - F” approximation of Eq. (4) violates the exact relationship. That violation does not provide a diagnostic as to whether it is the form of the pair of enhancement factors or the “2-F” approximation that is the cause. For example, if Eq. (3) were to be solved exactly but with a rather inaccurate F_τ to start, the result almost certainly would be inaccurate forces in AIMD simulations. This follows, in part, from the fact that Eq. (3) results from interchange of integration and differentiation.

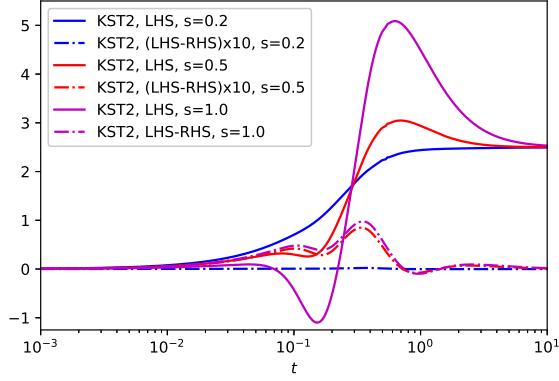


FIG. 1. Values of the left side of Eq. (3) and the difference between the left and right sides of that equation. Note that the differences for $s = 0.2$ and $s = 0.5$ are magnified by 10.

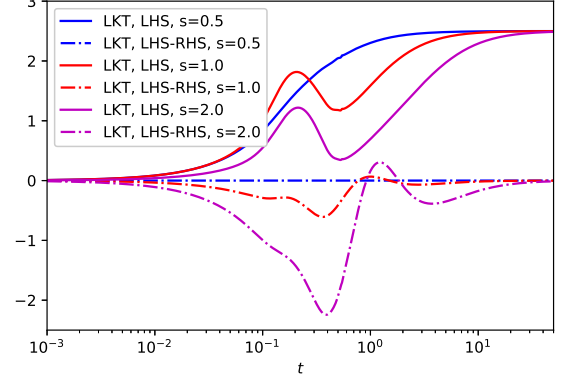


FIG. 2. As in Fig. (1) for LKTF but on a different range of s .

In turn that leads back to Eq. (45) of Ref. [1], namely the difference of entropic free energy between the thermodynamically correct entropic part from a given GGA and the contribution from the nominally entropic term:

$$\begin{aligned} T\Delta S_s := & \int \left[-\xi'(t)F_\tau(s_\tau) - \xi(t)F'_\tau(s_\tau)\frac{\partial s_\tau}{\partial t} \right. \\ & + \zeta'(t)F_\sigma(s_\sigma) + \zeta(t)F'_\sigma(s_\sigma)\frac{\partial s_\sigma}{\partial t} \\ & \left. - \frac{1}{t}\zeta(t)F_\sigma(s_\sigma) \right] t\tau_0^{\text{TF}}(n)d\mathbf{r}^3. \end{aligned} \quad (5)$$

From Table III, the largest violation happens around $T = 4\text{eV}$ for LKTF, and $T = 5\text{eV}$ for VT84F. Comparing the absolute value, the violation for LKTF is certainly not worse than VT84F.

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TABLE III. The deviation $T\Delta S$ as computed in Ref. [1] for cd Si at $\rho = 2.0 \text{ g/cm}^3$. LKTF and VT84F are included. For higher densities, similar trends were observed.

T (eV)	TS^{LKTF} (eV)	$T\Delta S^{LKTF}$ (eV)	TS^{VT84F} (eV)	$T\Delta S^{VT84F}$ (eV)
01	11.37	0.39	12.68	1.23
02	42.89	0.75	46.28	2.84
03	95.80	1.29	103.52	5.65
04	168.42	1.71	180.50	8.29
05	256.04	1.51	269.66	8.57
06	355.14	1.04	367.76	7.00
07	463.55	0.58	473.94	4.83
08	579.61	0.23	587.25	2.58
09	702.18	0.02	707.32	0.86
10	830.37	-0.09	833.47	-0.29